


TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

# TLP185

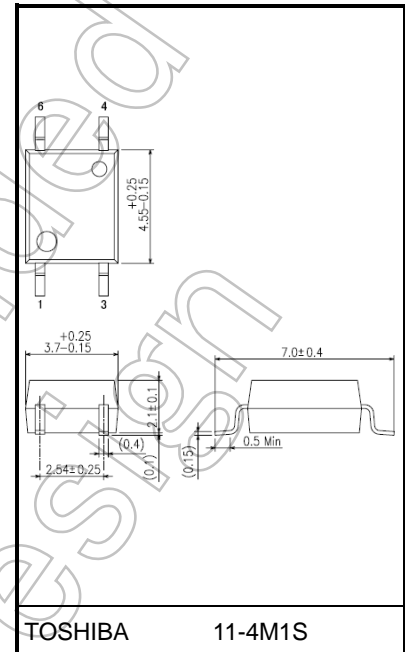
Office Machine  
 Programmable Controllers  
 AC Adapter  
 I/O Interface Board

The TOSHIBA mini flat coupler TLP185 is a small outline coupler, suitable for surface mount assembly. TLP185 consists of a photo transistor optically coupled to a gallium arsenide infrared emitting diode. Since TLP185 is smaller than DIP package, it's suitable for high-density surface mounting applications such as programmable controllers.

- Collector-emitter voltage: 80 V (min)
- Current transfer ratio: 50 % (min)  
 Rank GB: 100% (min)
- Isolation voltage: 3750 Vrms (min)
- Operation Temperature: -55 to 110 °C
- Safety Standards  
 UL approved: UL1577, File No. E67349  
 cUL approved: CSA Component Acceptance Service No. 5A  
 File No. E67349
- CQC approved: GB4943.1, GB8898 Japan and Thailand Factory  
 仅适用于海拔 2000m 以下地区安全使用
- Option (V4) type  
 VDE approved: EN60747-5-5, EN60065, EN60950-1 (Note 1)  
 Under application EN62368-1  
 Note 1: When a EN60747-5-5 approved type is needed,  
 Please designate "Option(V4)"

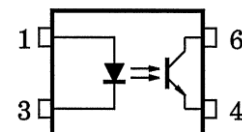
- Construction mechanical rating  
 Creepage distance : 5.0 mm (min)  
 Clearance : 5.0 mm (min)  
 Insulation thickness : 0.4 mm (min)

Unit: mm



Weight: 0.08 g (typ.)

### Pin Configuration (top view)



- 1: Anode
- 3: Cathode
- 4: Emitter
- 6: Collector

Start of commercial production  
 2011-12

## Current Transfer Ratio

Type	Classification (Note1)	Current Transfer Ratio (%) ( $I_C / I_F$ )		Marking Of Classification
		$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}, T_a = 25^\circ\text{C}$		
		Min	Max	
TLP185	Blank	50	400	Blank, YE, GR, GB, Y+, G, G+, B
	Rank Y	50	150	YE, Y+
	Rank GR	100	300	GR, G, G+
	Rank GB	100	400	GB, GR, G, G+, BL, B,
	Rank YH	75	150	Y+
	Rank GRL	100	200	G
	Rank GRH	150	300	G+
	Rank BLL	200	400	B

Note1: Ex Rank GB: TLP185 (GB,E)

Note: Application, type name for certification test, please use standard product type name, i. e.  
TLP185(GB,E: TLP185

Not Recommended for New Design

## Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I <sub>F</sub>	50	mA
	Forward current derating (Ta ≥ 90°C)	ΔI <sub>F</sub> /°C	-1.5	mA/°C
	Pulse forward current (Note 1)	I <sub>FP</sub>	1	A
	Reverse voltage	V <sub>R</sub>	5	V
	Diode power dissipation	P <sub>D</sub>	100	mW
	Diode power dissipation derating (Ta >90°C)	ΔP <sub>D</sub> /°C	-2.9	mW/°C
	Junction temperature	T <sub>j</sub>	125	°C
Detector	Collector-emitter voltage	V <sub>CEO</sub>	80	V
	Emitter-collector voltage	V <sub>ECO</sub>	7	V
	Collector current	I <sub>C</sub>	50	mA
	Collector power dissipation	P <sub>C</sub>	150	mW
	Collector power dissipation derating (Ta ≥ 25°C)	ΔP <sub>C</sub> /°C	-1.5	mW/°C
	Junction temperature	T <sub>j</sub>	125	°C
Operating temperature range		T <sub>opr</sub>	-55 to 110	°C
Storage temperature range		T <sub>stg</sub>	-55 to 125	°C
Lead soldering temperature (10 s)		T <sub>sol</sub>	260	°C
Total package power dissipation		P <sub>T</sub>	200	mW
Total package power dissipation derating (Ta ≥ 25°C)		ΔP <sub>T</sub> /°C	-2.0	mW/°C
Isolation voltage (AC, 60 s, R.H. ≤ 60%) (Note 2)		BV <sub>S</sub>	3750	V <sub>rms</sub>

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width ≤ 100 μs, f = 100 Hz

Note 2: Device considered a two terminal device: Pins 1 and 3 shorted together and 4 and 6 shorted together.

## Recommended Operating Conditions

Characteristic	Symbol	Min	Typ.	Max	Unit
Supply voltage	V <sub>CC</sub>	—	5	48	V
Forward current	I <sub>F</sub>	—	16	20	mA
Collector current	I <sub>C</sub>	—	1	10	mA

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

## Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.1	1.25	1.4	V
	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	—	—	5	μA
	Capacitance	C <sub>T</sub>	V = 0 V, f = 1 MHz	—	30	—	pF
Detector	Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 0.5 mA	80	—	—	V
	Emitter-collector breakdown voltage	V <sub>(BR)ECO</sub>	I <sub>E</sub> = 0.1 mA	7	—	—	V
	Collector dark current	I <sub>CEO</sub>	V <sub>CE</sub> = 48 V	—	0.01	0.08	μA
			V <sub>CE</sub> = 48 V, Ta = 85°C	—	2	50	μA
Capacitance (collector to emitter)	C <sub>CE</sub>	V = 0 V, f = 1 MHz	—	10	—	pF	

## Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Current transfer ratio	I <sub>C</sub> /I <sub>F</sub>	I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V Rank GB	50	—	400	%
			100	—	400	
Saturated CTR	I <sub>C</sub> /I <sub>F(sat)</sub>	I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 0.4 V Rank GB	—	60	—	%
			30	—	—	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 2.4 mA, I <sub>F</sub> = 8 mA	—	—	0.3	V
		I <sub>C</sub> = 0.2 mA, I <sub>F</sub> = 1 mA Rank GB	—	0.2	—	
			—	—	0.3	
Off-state collector current	I <sub>C(off)</sub>	V <sub>F</sub> = 0.7 V, V <sub>CE</sub> = 48 V	—	1	10	μA

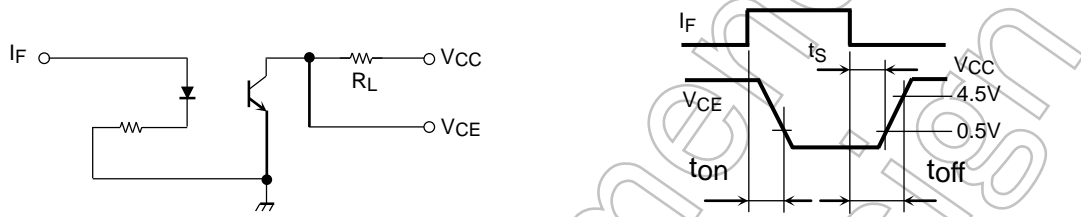
## Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance (input to output)	C <sub>S</sub>	V <sub>S</sub> = 0 V, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≤ 60%	1×10 <sup>12</sup>	10 <sup>14</sup>	—	Ω
Isolation voltage	BV <sub>S</sub>	AC, 60 s	3750	—	—	V <sub>rms</sub>
		AC, 1 s, in oil	—	10000	—	V <sub>dc</sub>
		DC, 60 s, in oil	—	10000	—	

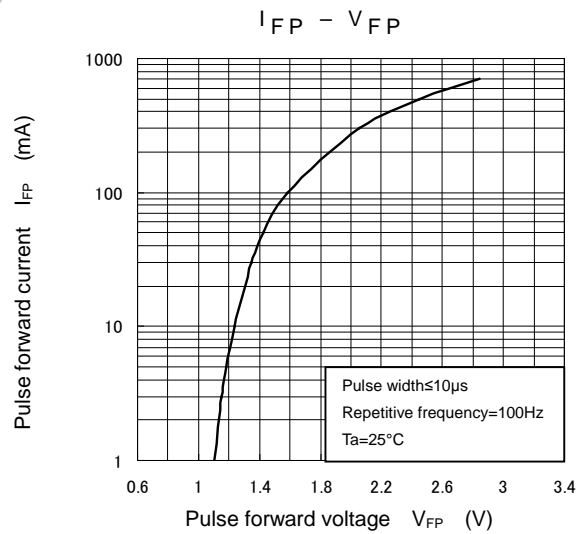
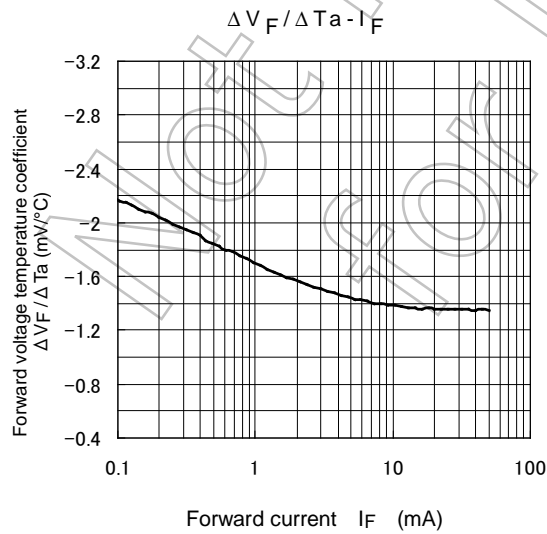
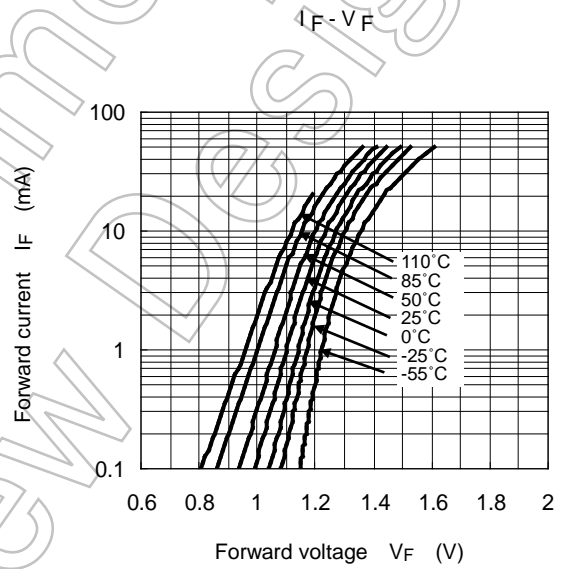
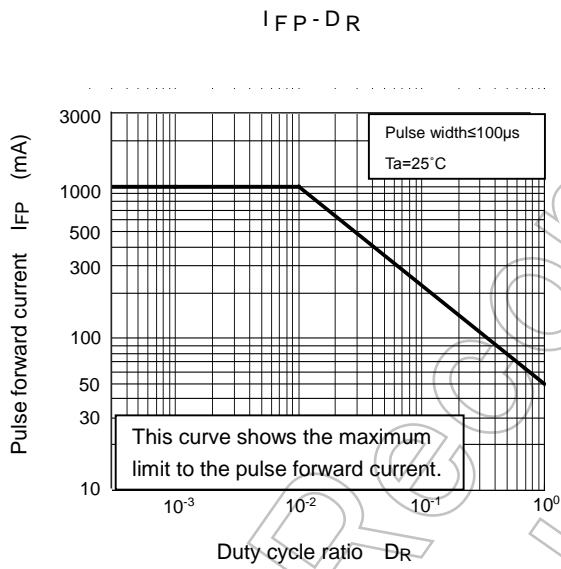
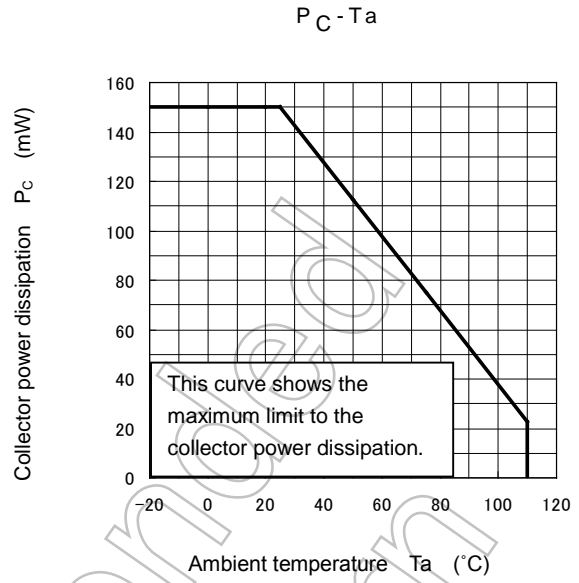
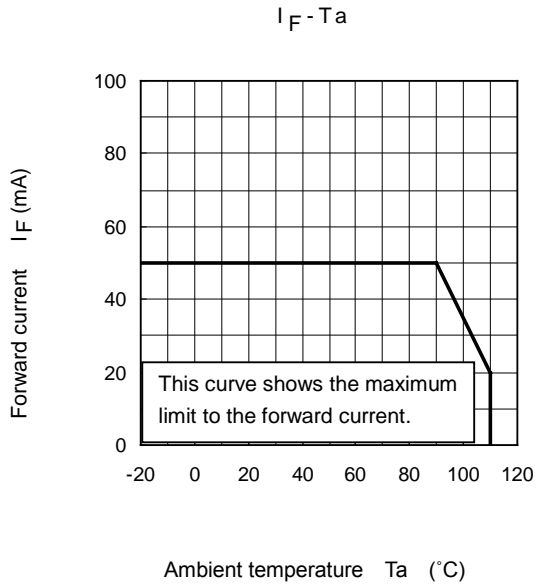
**Switching Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Rise time	$t_r$	$V_{CC} = 10\text{ V}$ , $I_C = 2\text{ mA}$ $R_L = 100\ \Omega$	—	5	—	$\mu\text{s}$
Fall time	$t_f$		—	9	—	
Turn-on time	$t_{on}$		—	9	—	
Turn-off time	$t_{off}$		—	9	—	
Turn-on time	$t_{on}$	$R_L = 1.9\text{ k}\Omega$ $V_{CC} = 5\text{ V}$ , $I_F = 16\text{ mA}$ (Fig.1)	—	2	—	$\mu\text{s}$
Storage time	$t_s$		—	30	—	
Turn-off time	$t_{off}$		—	70	—	

Fig. 1 Switching time test circuit

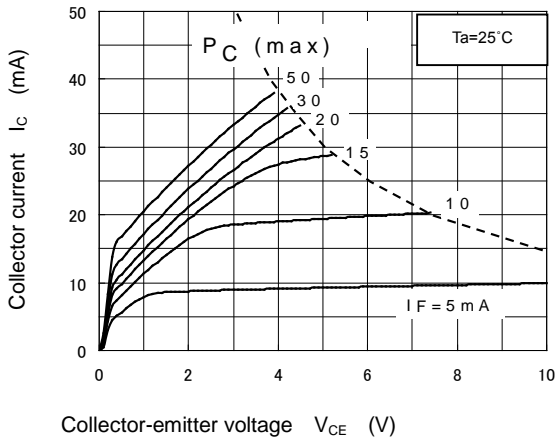


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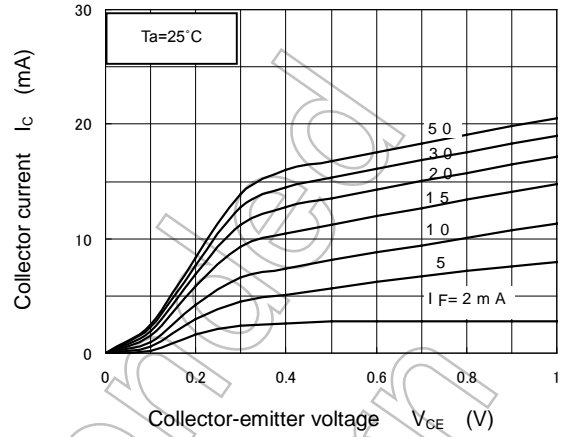


\*The above graphs show typical characteristic.

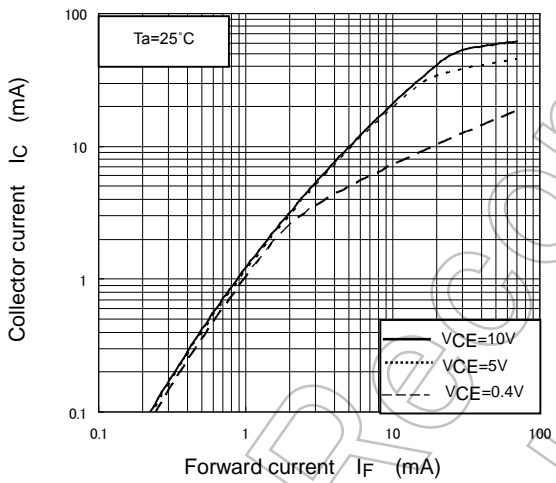
$I_C - V_{CE}$



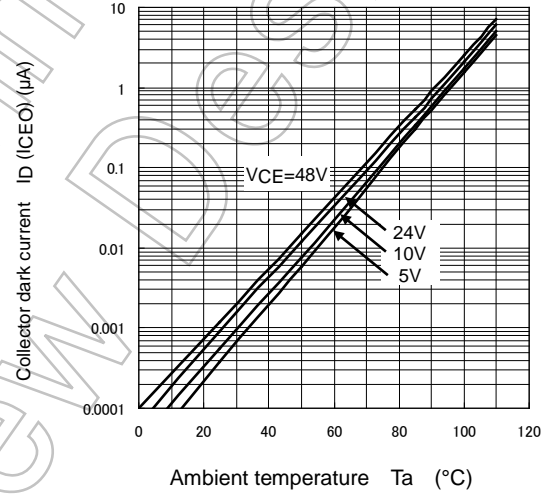
$I_C - V_{CE}$



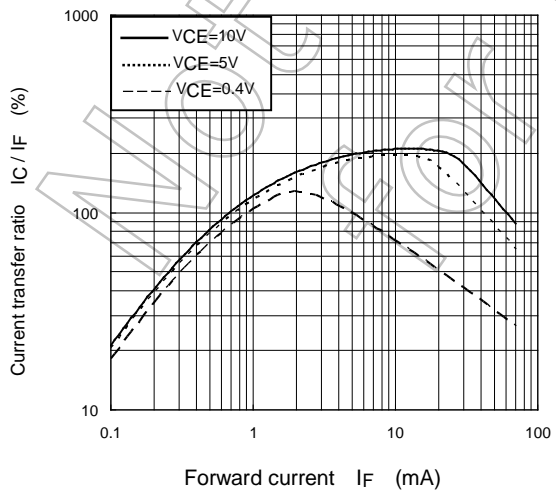
$I_C - I_F$



$I_{CEO} - T_a$

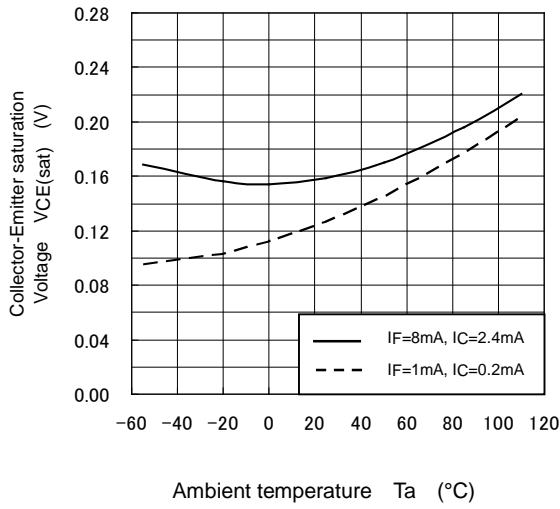


$I_C / I_F - I_F$

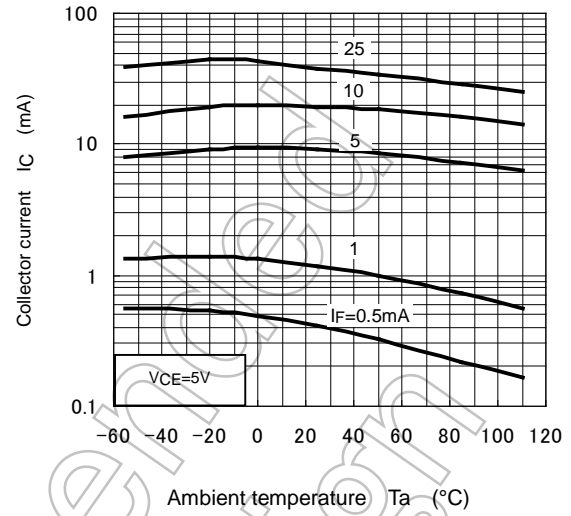


\*The above graphs show typical characteristic.

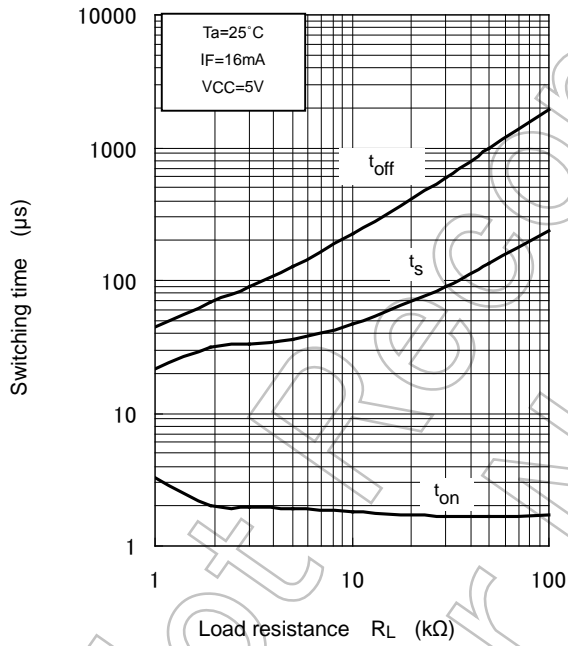
$V_{CE(sat)} - T_a$



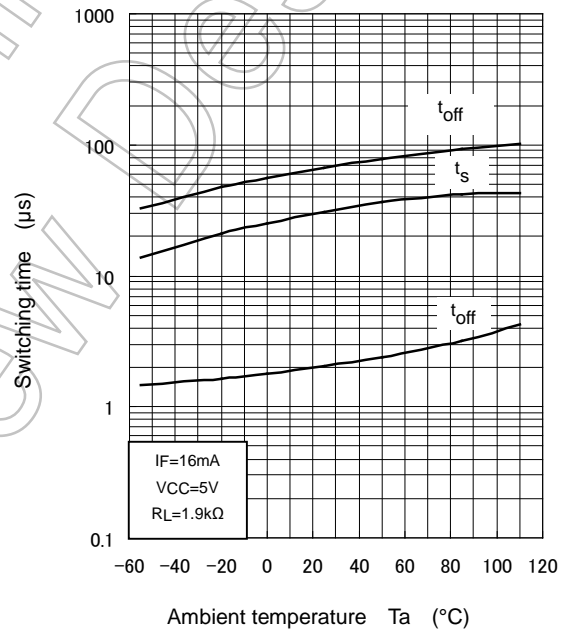
$I_C - T_a$



Switching time -  $R_L$



Switching time -  $T_a$



\*The above graphs show typical characteristic.



## Soldering and Storage

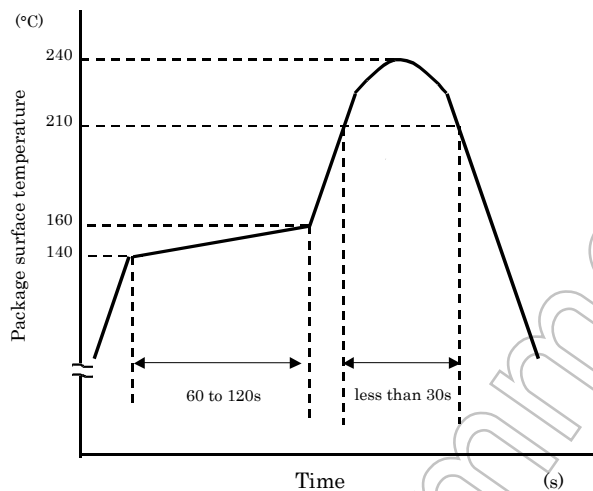
### 1. Soldering

#### 1.1 Soldering

When using a soldering iron or medium infrared ray/hot air reflow, avoid a rise in device temperature as much as possible by observing the following conditions.

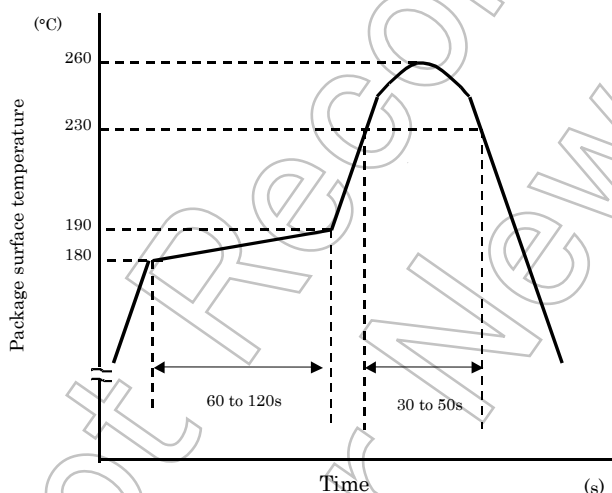
#### 1) Using solder reflow

·Temperature profile example of lead (Pb) solder



This profile is based on the device's maximum heat resistance guaranteed value. Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

·Temperature profile example of using lead (Pb)-free solder



This profile is based on the device's maximum heat resistance guaranteed value. Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

#### 2) Using solder flow (for lead (Pb) solder, or lead (Pb)-free solder)

Please preheat it at 150°C between 60 and 120 seconds.

Complete soldering within 10 seconds below 260°C. Each pin may be heated at most once.

#### 3) Using a soldering iron

Complete soldering within 10 seconds below 260°C, or within 3 seconds at 350°C. Each pin may be heated at most once.

## 2. Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.
- 3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

Not Recommended  
for New Design

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